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With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

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Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

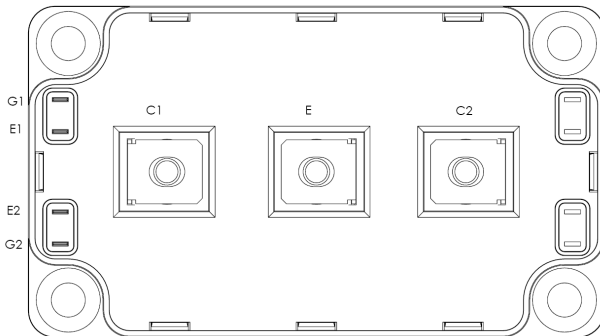
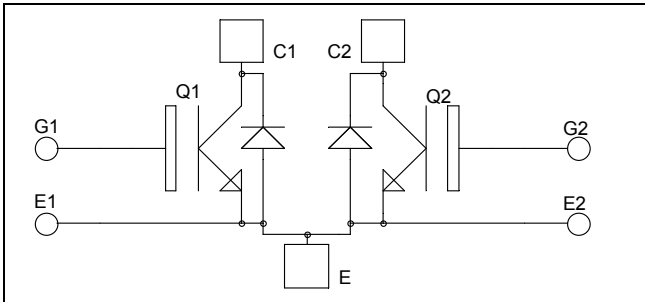
Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



**Dual common source  
Trench + Field Stop IGBT3  
Power Module**

**$V_{CES} = 1700V$   
 $I_C = 300A @ T_c = 80^\circ C$**



### Application

- AC Switches
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

### Features

- Trench + Field Stop IGBT3 Technology
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Soft recovery parallel diodes
  - Low diode VF
  - Low leakage current
  - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration

### Benefits

- Stable temperature behavior
- Very rugged
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- RoHS Compliant

### Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
$V_{CES}$	Collector - Emitter Breakdown Voltage	1700	V
$I_C$	Continuous Collector Current	$T_c = 25^\circ C$	400
		$T_c = 80^\circ C$	300
$I_{CM}$	Pulsed Collector Current	$T_c = 25^\circ C$	600
$V_{GE}$	Gate - Emitter Voltage	$\pm 20$	V
$P_D$	Maximum Power Dissipation	$T_c = 25^\circ C$	1660
RBSOA	Reverse Bias Safe Operating Area	$T_j = 125^\circ C$	600A @ 1600V

**CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on [www.microsemi.com](http://www.microsemi.com)

All ratings @  $T_j = 25^\circ\text{C}$  unless otherwise specified

**Electrical Characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$I_{CES}$	Zero Gate Voltage Collector Current	$V_{GE} = 0\text{V}, V_{CE} = 1700\text{V}$			750	$\mu\text{A}$
$V_{CE(sat)}$	Collector Emitter Saturation Voltage	$V_{GE} = 15\text{V}$ $I_C = 300\text{A}$		2.0	2.4	V
		$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$		2.4		
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}, I_C = 5\text{mA}$	5.0	5.8	6.5	V
$I_{GES}$	Gate – Emitter Leakage Current	$V_{GE} = 20\text{V}, V_{CE} = 0\text{V}$			600	nA

**Dynamic Characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$C_{ies}$	Input Capacitance	$V_{GE} = 0\text{V}$		26.5		nF
$C_{oes}$	Output Capacitance	$V_{CE} = 25\text{V}$		1.1		
$C_{res}$	Reverse Transfer Capacitance	$f = 1\text{MHz}$		0.88		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching ( $25^\circ\text{C}$ )		370		ns
$T_r$	Rise Time	$V_{GE} = 15\text{V}$ $V_{Bus} = 900\text{V}$		40		
$T_{d(off)}$	Turn-off Delay Time	$I_C = 300\text{A}$		650		
$T_f$	Fall Time	$R_G = 2.2\Omega$		180		
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching ( $125^\circ\text{C}$ )		400		ns
$T_r$	Rise Time	$V_{GE} = 15\text{V}$ $V_{Bus} = 900\text{V}$		50		
$T_{d(off)}$	Turn-off Delay Time	$I_C = 300\text{A}$		800		
$T_f$	Fall Time	$R_G = 2.2\Omega$		300		
$E_{on}$	Turn-on Switching Energy	$V_{GE} = 15\text{V}$ $V_{Bus} = 900\text{V}$		96		mJ
$E_{off}$	Turn-off Switching Energy	$I_C = 300\text{A}$ $R_G = 2.2\Omega$		94		

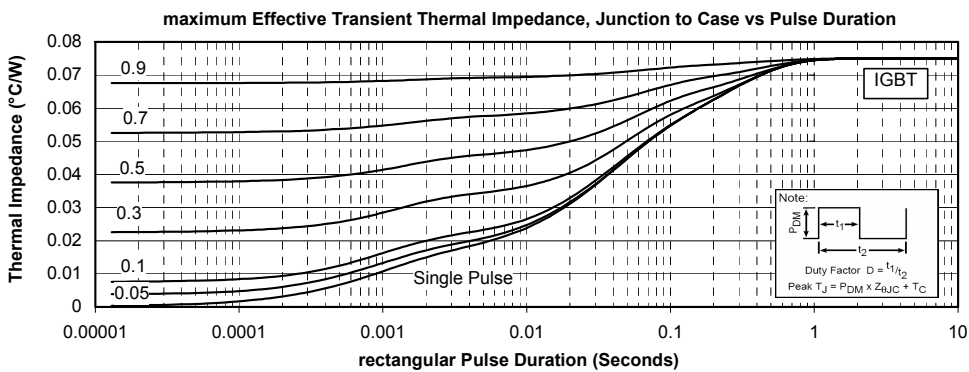
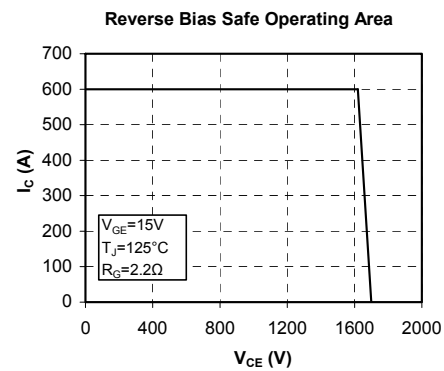
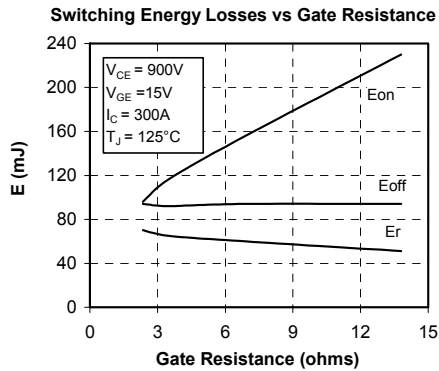
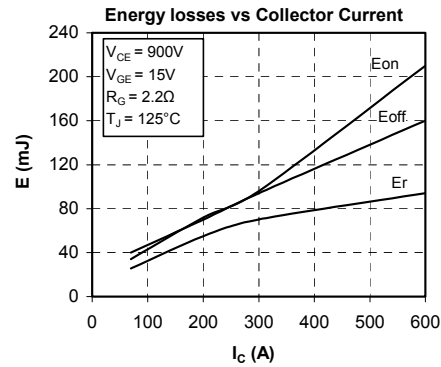
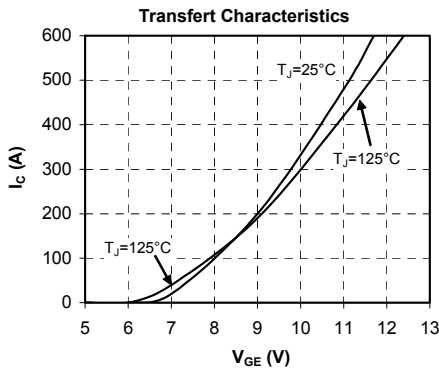
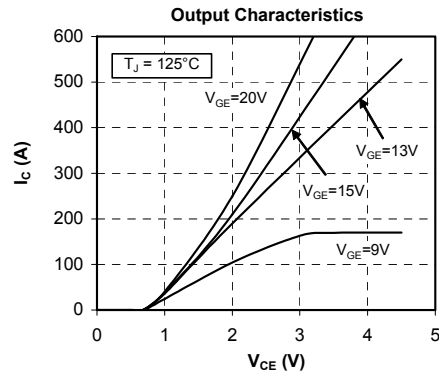
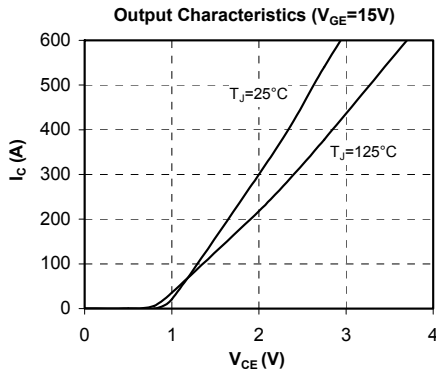
**Chopper diode ratings and characteristics**

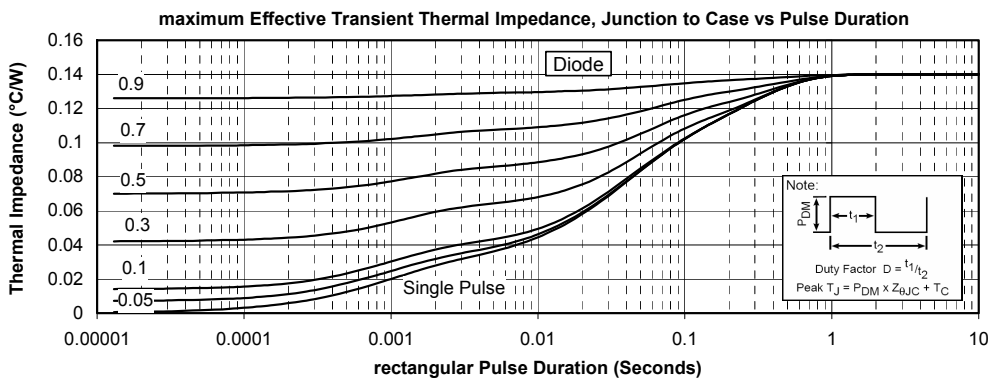
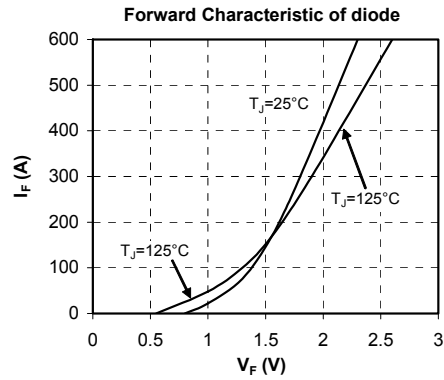
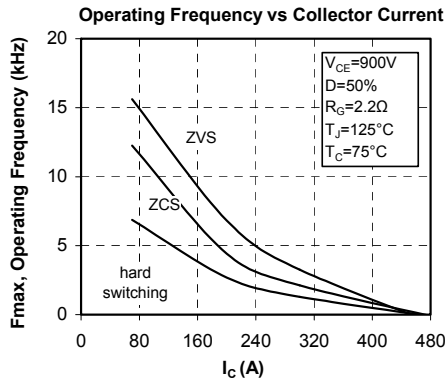
Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage		1700			V
$I_{RM}$	Maximum Reverse Leakage Current	$V_R = 1700\text{V}$			750	$\mu\text{A}$
		$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$			1000	
$I_F$	DC Forward Current			300		A
$V_F$	Diode Forward Voltage	$I_F = 300\text{A}$		1.8	2.2	V
		$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$		1.9		
$t_{rr}$	Reverse Recovery Time			385		ns
		$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$		490		
$Q_{rr}$	Reverse Recovery Charge	$I_F = 300\text{A}$ $V_R = 900\text{V}$ $di/dt = 3200\text{A}/\mu\text{s}$		76		$\mu\text{C}$
		$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$		124		
$E_r$	Reverse Recovery Energy			35		mJ
		$T_j = 25^\circ\text{C}$ $T_j = 125^\circ\text{C}$		70		





## Typical Performance Curve





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